


Trans RF FET N-CH 70V 3-Pin OM-780 EP T/R

Manufacturer:	NXP Semiconductor
Package/Case:	TO-59
Product Type:	Thyristors
RoHS:	RoHS Compliant/Lead free 
Lifecycle:	Obsolete



Images are for reference only

[Inquiry](#)

General Description

The MRF8S9102NR3 is designed for CDMA base station applications with frequencies from 865 to 960 MHz. Can be used in Class AB and Class C for all typical cellular base station modulation formats.

Key Features

100% PAR Tested for Guaranteed Output Power Capability

Characterized with Series Equivalent Large-Signal Impedance Parameters and Common Source S-Parameters

Internally Matched for Ease of Use

Integrated ESD Protection

Greater Negative Gate-Source Voltage Range for Improved Class C Operation

Designed for Digital Predistortion Error Correction Systems

Optimized for Doherty Applications

225°C Capable Plastic Package

RoHS Compliant

In Tape and Reel. R3 Suffix = 250 Units, 32 mm Tape Width, 13-inch Reel.



Recommended For You

MRF6VP11KHR5

NXP Semiconductor
TO-59

MRF8S21100HSR3

NXP Semiconductor
SMD

MRF6S20010NR1

NXP Semiconductor
SMD

MRFE6VP6300HR5

NXP Semiconductor
TO-59

MRFE6S9060NR1

NXP Semiconductor
SMD

MRFE6VP61K25HR6

NXP Semiconductor
TO-59

MRF6VP3450HR5

NXP Semiconductor
TO-59

MRF6S18060NR1

NXP Semiconductor
TO-59

MRFE6P3300HR3

NXP Semiconductor
TO-59

MRF7S38040HSR3

NXP Semiconductor
SMD

MRFE6S9205HSR3

NXP Semiconductor
TO-59

MRF9135LR3

NXP Semiconductor
TO-59

MRFE6VP100HR5

NXP Semiconductor

TO-59

MRFX1K80NR5

NXP Semiconductor

SMD

MRFE6VS25NR1

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